JL6976N8 Datasheet

Zhuhai Jieli Technology Co.,LTD

Version：1.0

Date：2021.12.03

JL6976N8 Features

CPU

- 32-bit DSP supports hardware Float Point Unit(FPU)
- Up to 160MHz programmable processor
- 64Vectored interrupts
- 4 Levels interrupt priority

DSP Audio Processing

- SBC, AAC Audio decodes supported for BT audio
- mSBC voice codec supported for BT phone
- Supports MP2, MP3, WMA, APE, FLAC, AAC, MP4, M4A, WAV, AIF, AIFC audio decoding
- Packet Loss Concealment (PLC) for voice processing
- Acoustic echo cancellation/suppression (AEC,AES)
- Single/Dual MIC Environmental Noise Cancellation (ENC)
- Multi-band DRC limiter
- 20-band EQ configuration for voice Effects

Audio Codec

- Two channels 24-bit DAC, SNR >= 101dB
- Two channels 24-bit ADC , SNR >= 92dB
- Sampling rates of 8KHz/11.025KHz/16KHz/22.05KHz/ 24KHz/32KHz/44.1KHz/48KHz are supported
- Two analog MIC amplifier, build-in MIC bias generator
- Supports two PDM digital MIC inputs
- One channel Stereo analog MUX
- Supports cap-less, single-ended, and differential mode at the DAC path
- Supports 16ohm and 32ohm Speaker loading

Bluetooth

- Compliant with Bluetooth V5.3+BR+EDR+BLE specification
- Meet class2 and class3 transmitting power requirement
- Support GFSK and π/4 DQPSK all packet types
- Provides amaximum+8dbm transmitting power
- receiver with -94dBm sensitivity
- Fast AGC for enhanced dynamic range
- Supports a2dp\avctp\avdtp\avrcp\hfp\spp\smp\att\gap \gatt\rfcomm\sdp\l2cap profile
- a2dp 1.3.2\avctp 1.4\avdtp 1.3\ avrcp 1.6.2\ hfp 1.8 \spp 1.2\rfcomm 1.1\pnp 1.3\ hid 1.1.1\sdp core5.3\l2cap core 5.3

Peripherals

- One full speed USB 2.0 OTG controller
- Six multi-function 32-bit timers, support capture and PWM mode
- Three full-duplex basic UART, support DMA mode
- One hard ware IIC interface supports host and device mode
- Built-in Cap Sense Key controller
- Two Built-in low power Cap Sense Keys
- 10-bit ADC for analog sampling
- External wake up/interrupt on all GPIOs

PMU

- Low voltage LDO and DC-DC for internal digital and analog circuit supply
- 2uA current consumption in the soft-off mode
- Built-in LDO and DC-DC for the core, I/O, Bluetooth and flash
- VBAT is 2.2V to 4.5V
- VDDIO is 2.2V to 3.4V

Packages

- QFN32(4mm*4mm)

Temperature

- Operating temperature: -40℃ to +85℃
- Storage temperature: -65℃ to +150℃

Applications

- Bluetooth wireless MIC
- Bluetooth Game Earphone

1、Pin Definition

1.1 Pin Assignment

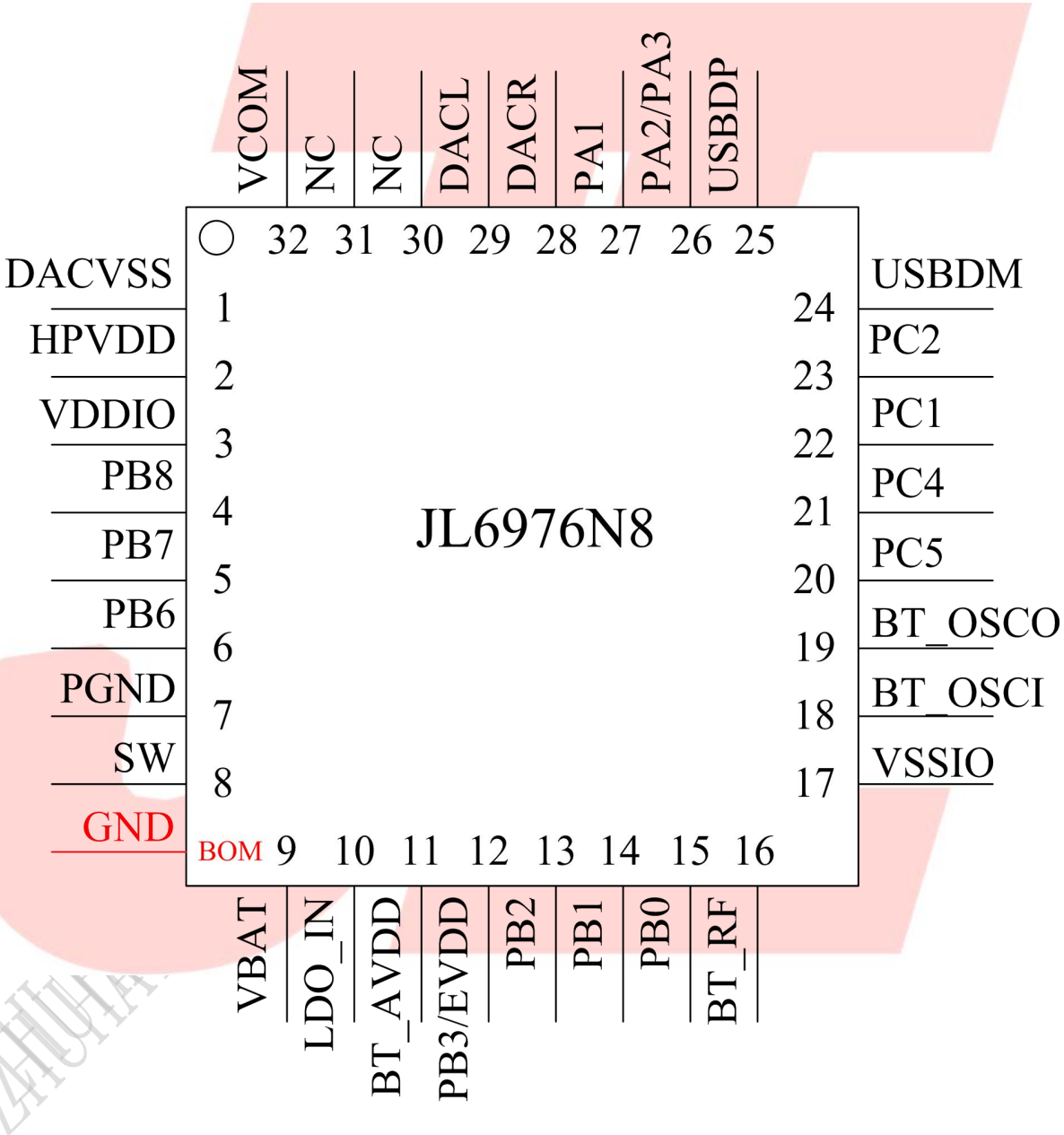


Figure 1-1 JL6976N8 Package Diagram

1.2 Pin Description

Table 1-1 JL6976N8 Pin Description

PIN NO.	Name	I/O Type	Drive (mA)	Function	Other Function
1	DACVSS	P	/		Analog Ground
2	HPVDD	P	/		Headphone AMP Power
3	VDDIO	P	/		IO Power 3.3v
4	PB8	I/O	8/24	GPIO	MIC1：MIC1 Input Channel； UART0RXB：Uart0 Data Input(B)； CAP4：Timer4 Capture；
5	PB7	I/O	8/24	GPIO	MIC_BIAS1：MIC1 Bias Output； UART0TXB：Uart0 Data Output(B);
6	PB6	I/O	8/24	GPIO	UART1RXA：Uart1 Data Input(A)； PWM2：Timer2 PWM Output； ADC9：ADC Input Channel 9； Touch7：Touch Input Channel 7;
7	PGND	P	/		DCDC Ground
8	SW	P	/		DCDC switch output, connected to inductor
9	VBAT	P	/		Power Supply, connect to battery
10	LDO_IN	P	/		Charge Power Input; UART0TXC：Uart0 Data Output(C); UART0RXC：Uart0 Data Input(C); PWM3：Timer3 PWM Output； CAP1：Timer1 Capture;
11	BT_AVDD	P	/	GPIO	BT Power
12	PB3	I/O	8/24	GPIO	
	EVDD	P	/		EVDD：Supply volte to peripherals
13	PB2	I/O	8/24	GPIO	UART2RXC：Uart2 Data Input(C); SPI2DOC：SPI2 Data Out(C); CAP5：Timer5 Capture; ADC7：ADC Input Channel 7； LP_TH1：Low Power Touch Channel 1
14	PB1	I/O	8/24	GPIO (pull up)	Long Press Reset； SPI2CLKC：SPI2 Clk(C); UART2TXC：Uart2 Data Output(C) ADC6：ADC Input Channel 6； LP_TH0：Low Power Touch Channel 0

15	PB0	I/O	8	GPIO (High Voltage Input)	SPI2_DIC：SPI2 Data In(C); ALNK_MCLK(B)：ALNK1 Master Clock(B); TMR4：Timer4 Clock Input;
16	BT_RF	/	/		BT Antenna
17	VSSIO	P	/		Ground
18	BT_OSCI	I	/		BTOSC In
19	BT_OSCO	O	/		BTOSC Out
20	PC5	I/O	8/24	GPIO	UART2RXD：Uart2 Data Input(D); SPI1DOB：SPI1 Data Out(B); ALNK_DAT3(B)：Audio Link Data3(B); IIC_SDA_B：IIC SDA(B)； ADC5：ADC Input Channel 5；
21	PC4	I/O	8/24	GPIO	UART2TXD：Uart2 Data Output(D); SPI1CLKB：SPI1 Clock(B); ALNK_DAT2(B)：Audio Link Data2(B); IIC_SCL_B：IIC SCL(B)； ADC4：ADC Input Channel 4； PWM4：Timer4 PWM Output；
22	PC1	I/O	8/24	GPIO	UART1RXB：Uart1 Data Input(B); SPI2DIB：SPI2 Data In(B); ALNK_DAT1(B)：Audio Link Data1(B); TMR5：Timer5 Clock Input;
23	PC2	I/O	8/24	GPIO	ALNK_SCLK(B)：Audio Link Serial Clock(B); IIC_SCL_C：IIC SCL(C)； UART0TXD：Uart0 Data Output(D); TMR1：Timer1 Clock Input;
24	USBDM	I/O	4	USB Negative Data	UART1RXD：Uart1 Data Input(D)； IIC_SDA_A：IIC SDA(A)； ADC11：ADC Input Channel 11；
25	USBDP	I/O	4	USB Positive Data	UART1TXD：Uart1 Data Output(D)； IIC_SCL_A：IIC SCL(A)； ADC10：ADC Input Channel 10；
26	PA3	I/O	8/24	GPIO	UART2TXA：Uart2 Data Output(A); ADC0：ADC Input Channel 0； PWM1：Timer1 PWM Output； Touch0：Touch Input Channel 0;
	PA2	I/O	8/24	GPIO	ALNK_MCLK(A)：ALNK Master Clock(A); MIC_BIAS0：MIC0 Bias Output； MIC0_N：Different MIC0 Negative CAP3：Timer3 Capture； UART1RXC： Uart1 Data In(C)；
27	PA1	I/O	8/24	GPIO	MIC0：MIC0 Input Channel ;

					PWM0：Timer0 PWM Output； UART1TXC：Uart1 Data Output(C)；
28	DACR	O	/		DAC Right Channel
29	DACL	O	/		DAC Left Channel
30	NC				
31	NC				
32	VCOM	P	/		DAC reference voltage

2、Electrical Characteristics

2.1 Absolute Maximum Ratings

Table 2-1

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-40	+85	℃
Tstg	Storage temperature	-65	+150	℃
VBAT	Supply Voltage	-0.3	4.5	V
LDO_IN	Charger Voltage	-0.3	6	V
$V_{3.3IO}$	3.3V IO Input Voltage	-0.3	3.6	V

Note : The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

2.2 PMU Characteristics

Table 2-2

Symbol	Parameter	Min	Typ	Max	Unit	Test Conditions
VBAT	Voltage Input	2.2	3.7	4.2	V	
LDO_IN	Charger supply Voltage	4.5	5.0	5.5	V	
Normal mode						
VDDIO	Voltage output	_	3.0	_	V	VBAT = 4.2V, 10mA loading
	Loading current	_	_	100	mA	VDDIO=3V@VBAT = 4.2V
BT_AVDD	Voltage output	_	1.3	_	V	VDDIO=3.0V, 10mA loading
	Loading current	_	_	60	mA	BT_AVDD=1.25V@VDDIO=3.0v
EVDD	Voltage output	_	1.1	_	V	BT_AVDD=1.25V, 1mA loading
	Loading current	_	_	5	mA	EVDD=1.1V@BT_AVDD=1.25v
LP mode						
VDDIO	Loading current			5	mA	VDDIO=3V@VBAT = 4.2V

2.3 Battery Charge

Table 2-3

Symbol	Parameter	Min	Typ	Max	Unit	Test Conditions
LDO_IN	Charge Input Voltage	4.5	5	5.5	V	_
V_{Charge}	Charge Voltage	4.15	4.2	4.25	V	LDO_IN＞4.5V

		4.30	4.35	4.40	V	LDO_IN＞4.65V
I_{Charge}	Charge Current	20		200	mA	Charge current at fast charge mode
I_{Trikl}	Trickle Charge Current	20	45	70	mA	$V_{BAT}<V_{Trikl}$

2.4 IO Input/Output Electrical Logical Characteristics

Table 2-4

IO input characteristics						
Symbol	**Parameter**	**Min**	**Typ**	**Max**	**Unit**	**Test Conditions**
V_{IL}	Low-Level Input Voltage	-0.3	_	0.3* VDDIO	V	VDDIO = 3.3V
V_{IH}	High-Level Input Voltage	0.7* VDDIO	_	VDDIO+0.3	V	VDDIO = 3.3V
IO output characteristics						
V_{OL}	Low-Level Output Voltage	_	_	0.33	V	VDDIO = 3.3V
V_{OH}	High-Level Output Voltage	2.7	_	_	V	VDDIO = 3.3V

2.5 Internal Resistor Characteristics

Table 2-5

Port	**General Output**	**High Drive**	**Internal Pull-Up Resistor**	**Internal Pull-Down Resistor**	**Comment**
PA1~PA3 PC2~PC5 PB3~PB3 PB6~PB8	8mA	24mA	10K	10K	1、PB1 default pull up 2、USBDM & USBDP default pull down 3、internal pull-up/pull-down resistance | accuracy ±20%
PB0	8mA	_	10K	10K	
USBDP	4mA	_	1.5K	15K	
USBDM	4mA	_	180K	15K	

2.6 DAC Characteristics

Table 2-6

Parameter	**Min**	**Typ**	**Max**	**Unit**	**Test Conditions**
Frequency Response	20	_	20K	Hz	1KHz/0dB 10Kohm loading With A-Weighted Filter
THD+N	_	-80	_	dB	
S/N	_	101	_	dB	
Crosstalk	_	-80	_	dB	

Output Swing		0.45		Vrms	
Dynamic Range		90		dB	1KHz/-60dB 10Kohm loading With A-Weighted Filter
DAC Output Power	_	4	_	mW	32ohm loading

2.7 ADC Characteristics

Table 2-7

Parameter	Min	Typ	Max	Unit	Test Conditions
Dynamic Range		92		dB	Fsample=44.1kHz Fin=1KHz 2mVpp Input
S/N	_	92	_	dB	Fsample=44.1kHz Fin=1KHz 1.2Vpp Input
THD+N	_	-75	_	dB	
Crosstalk	_	-80	_	dB	

2.8 BT Characteristics

2.8.1 Transmitter

Basic Data Rate **Table 2-8**

Parameter		Min	Typ	Max	Unit	Test Conditions
RF Transmit Power			6	8	dBm	25℃, Power Supply VBAT=5V 2441MHz
RF Power Control Range			20		dB	
20dB Bandwidth			950		KHz	
Adjacent Channel Transmit Power	+2MHz		-40		dBm	
	-2MHz		-38		dBm	
	+3MHz		-44		dBm	
	-3MHz		-35		dBm	

Enhanced Data Rate **Table 2-9**

Parameter		Min	Typ	Max	Unit	Test Conditions
Relative Power			-1		dB	25℃, Power Supply VBAT=5V 2441MHz
π/4 DQPSK Modulation Accuracy	DEVM RMS		6		%	
	DEVM 99%		10		%	
	DEVM Peak		15		%	
Adjacent Channel Transmit Power	+2MHz		-40		dBm	
	-2MHz		-38		dBm	

	+3MHz		-44		dBm	
	-3MHz		-35		dBm	

2.8.2 Receiver

Basic Data Rate **Table 2-10**

Parameter		Min	Typ	Max	Unit	Test Conditions
Sensitivity			-94		dBm	25℃, Power Supply VBAT=5V 2441MHz
Co-channel Interference Rejection			-13		dB	
Adjacent Channel Interference Rejection	+1MHz		+5		dB	
	-1MHz		+2		dB	
	+2MHz		+37		dB	
	-2MHz		+36		dB	
	+3MHz		+40		dB	
	-3MHz		+35		dB	

Enhanced Data Rate **Table 2-11**

Parameter		Min	Typ	Max	Unit	Test Conditions
Sensitivity			-94		dBm	25℃, Power Supply VBAT=5V 2441MHz
Co-channel Interference Rejection			-13		dB	
Adjacent Channel Interference Rejection	+1MHz		+5		dB	
	-1MHz		+2		dB	
	+2MHz		+37		dB	
	-2MHz		+36		dB	
	+3MHz		+40		dB	
	-3MHz		+35		dB	

2.8.3 BLE Transmitter

1M Data Rate **Table 2-12**

Parameter		Min	Typ	Max	Unit	Test Conditions
Sensitivity			-94		dBm	25℃, Power Supply VBAT=5V 2441MHz
RF Transmit Power			7	9	dB	
In-band Spurious Emission	+2MHz		-42	-20	dB	
	-2MHz		-34	-20	dB	
	+3MHz		-46	-30	dB	
	-3MHz		-36	-30	dB	
Modulation	Δf1 avg	225	247			

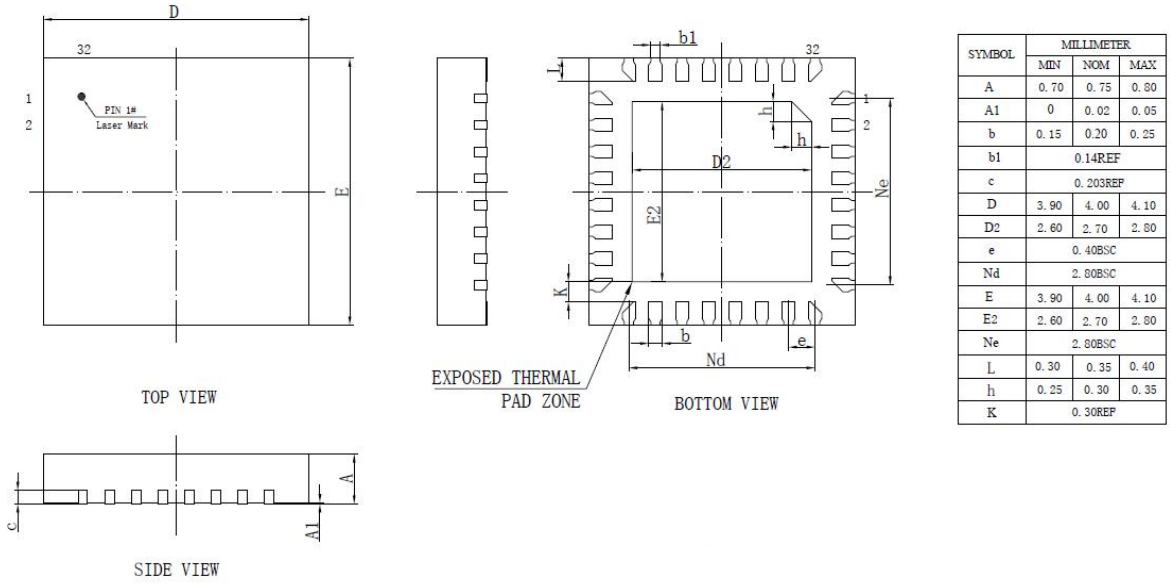
	Δf2 99%	185	236			
	Δf1avg/Δf2av	0.8	0.9			
Carrier Frequency Offset		-150	+/-10	+150	KHz	
Frequency Drift		-50	+/-5	+50	KHz	
Frequency Drift Rate		-20	3	+20	KHz/50us	

2M Data Rate **Table 2-13**

Parameter		Min	Typ	Max	Unit	Test Conditions
Sensitivity			-94		dBm	
RF Transmit Power			7	9	dB	
Adjacent Channel Transmit	+2MHz		-46	-20	dB	
	-2MHz		-38	-20	dB	
	+3MHz		-53	-30	dB	25℃, Power Supply VBAT=5V 2441MHz
	-3MHz		-42	-30	dB	
Frequency Deviation	Δf1 avg	450	520			
	Δf2 99%	370	500			
	Δf1avg/Δf2av	0.8	0.9			
Carrier Frequency Offset		-150	+/-10	+150	KHz	
Frequency Drift		-50	+/-5	+50	KHz	
Frequency Drift Rate		-20	+/-3	+20	KHz/50us	

3、Package Information

3.1 QFN32_4.0x4.0



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	0.70	0.75	0.80
A1	0	0.02	0.05
b	0.15	0.20	0.25
b1	0.14REF		
c	0.203REF		
D	3.90	4.00	4.10
D2	2.60	2.70	2.80
e	0.40BSC		
Nd	2.80BSC		
E	3.90	4.00	4.10
E2	2.60	2.70	2.80
Ne	2.80BSC		
L	0.30	0.35	0.40
h	0.25	0.30	0.35
K	0.30REF		

Figure 3-1 JL6976N8 Package

4、Revision History

Date	Revision	Description
2021.12.3	V1.0	Initial Release